

# SILICON POWER TRANSISTOR 2SC4551

## NPN SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SC4551 is a power transistor developed for high-speed switching and features low V<sub>CE(sat)</sub> and high h<sub>FE</sub>. This transistor is ideal for use in drivers such as DC/DC converters and actuators.

In addition, a small resin-molded insulation type package contributes to high-density mounting and reduction of mounting cost.

#### **FEATURES**

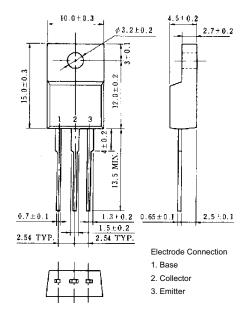
- High hre and low  $V_{CE(sat)}$ : hre  $\geq$  100 ( $V_{CE}=2$  V,  $I_{C}=2$  A)  $V_{CE(sat)} \leq 0.3$  V ( $I_{C}=6$  A,  $I_{B}=0.3$  A)
- Mold package that does not require an insulating board or insulation bushing

#### ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	V <sub>СВО</sub>	100	V
Collector to emitter voltage	Vceo	60	V
Emitter to base voltage	V <sub>EBO</sub>	7.0	V
Collector current (DC)	I <sub>C(DC)</sub>	10	Α
Collector current (pulse)	Ic(pulse)*	20	Α
Base current (DC)	I <sub>B(DC)</sub>	5.0	Α
Total power dissipation	P <sub>T</sub> (Tc = 25°C)	30	W
Total power dissipation	P⊤ (Ta = 25°C)	2.0	W
Junction temperature	Tj	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

<sup>\*</sup> PW  $\leq$  300  $\mu$ s, duty cycle  $\leq$  10%

#### PACKAGE DRAWING (UNIT: mm)



The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.



#### **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

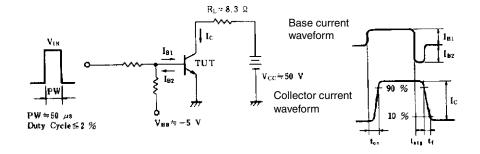
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	VCEO(SUS)	Ic = 6.0 A, Iв = 0.6 A, L = 1 mH	60			V
Collector to emitter voltage	VCEX(SUS)	Ic = 6.0 A, I <sub>B1</sub> = $-I_{B2}$ = 0.6 A, V <sub>BE(OFF)</sub> = $-1.5$ V, L = 180 $\mu$ H, clamped	60			V
Collector cutoff current	Ісво	V <sub>CB</sub> = 60 V, I <sub>E</sub> = 0			10	μΑ
Collector cutoff current	ICER	VcE = 60 V, RBE = 50 Ω, Ta = 125°C			1.0	mA
Collector cutoff current	ICEX1	VCE = 60 V, VBE(OFF) = -1.5 V			10	μΑ
Collector cutoff current	ICEX2	$V_{CE} = 60 \text{ V}, V_{BE(OFF)} = -1.5 \text{ V},$ $Ta = 125^{\circ}C$			1.0	mA
Emitter cutoff current	ІЕВО	VEB = 5.0 V, Ic = 0			10	μΑ
DC current gain	h <sub>FE1</sub> *	VcE = 2.0 V, Ic = 1.0 A	100			
DC current gain	h <sub>FE2</sub> *	VcE = 2.0 V, Ic = 2.0 A	100	200	400	
DC current gain	h <sub>FE3</sub> *	Vce = 2.0 V, lc = 6.0 A	60			
Collector saturation voltage	V <sub>CE(sat)1</sub> *	Ic = 6.0 A, I <sub>B</sub> = 0.3 A			0.3	V
Collector saturation voltage	VCE(sat)2*	Ic = 8.0 A, IB = 0.4 A			0.5	V
Base saturation voltage	V <sub>BE(sat)1</sub> *	Ic = 6.0 A, I <sub>B</sub> = 0.3 A			1.2	V
Base saturation voltage	V <sub>BE(sat)2</sub> *	Ic = 8.0 A, I <sub>B</sub> = 0.4 A			1.5	V
Collector capacitance	Cob	VcB = 10 V, IE = 0, f = 1.0 MHz		150		pF
Gain bandwidth product	f⊤	VcE = 10 V, Ic = 1.0 A		140		MHz
Turn-on time	ton	Ic = 6.0 A, R <sub>L</sub> = 8.3 Ω,			0.3	μs
Storage time	tstg	I <sub>B1</sub> = −I <sub>B2</sub> = 0.3 A, V <sub>CC</sub> ≅ 50 V Refer to the test circuit.			1.5	μs
Fall time	tf	nelei to the test circuit.			0.3	μs

<sup>\*</sup> Pulse test PW  $\leq$  350  $\mu$ s, duty cycle  $\leq$  2%

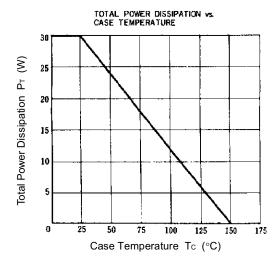
#### **hfe CLASSIFICATION**

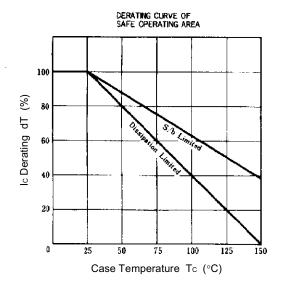
Marking	М	L	K
h <sub>FE2</sub>	100 to 200	150 to 300	200 to 400

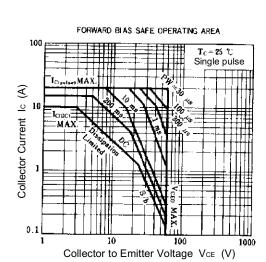
### SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT

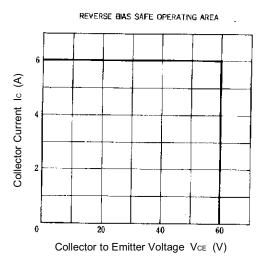


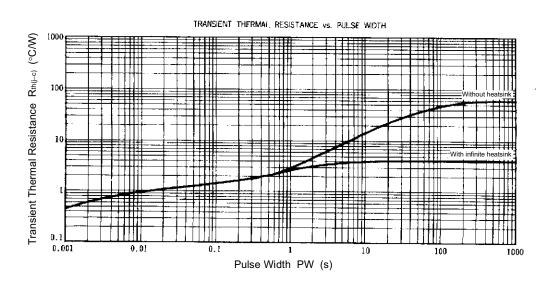
#### TYPICAL CHARACTERISTICS (Ta = 25°C)

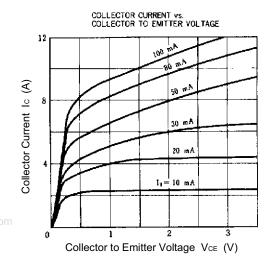


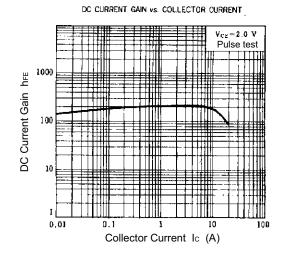


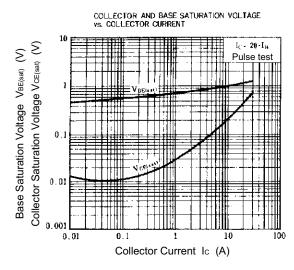


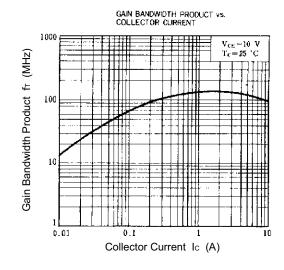


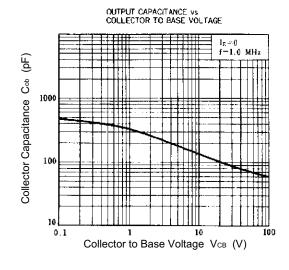


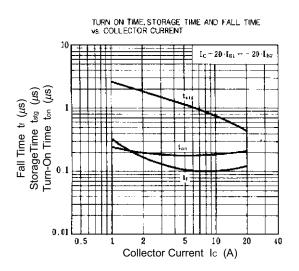












[MEMO]

www.DataSheet/II.com

www.DataSheet4LLcon

- The information in this document is current as of July, 2001. The information is subject to change
  without notice. For actual design-in, refer to the latest publications of NEC's data sheets or data
  books, etc., for the most up-to-date specifications of NEC semiconductor products. Not all products
  and/or types are available in every country. Please check with an NEC sales representative for
  availability and additional information.
- No part of this document may be copied or reproduced in any form or by any means without prior written consent of NEC. NEC assumes no responsibility for any errors that may appear in this document.
- NEC does not assume any liability for infringement of patents, copyrights or other intellectual property rights of
  third parties by or arising from the use of NEC semiconductor products listed in this document or any other
  liability arising from the use of such products. No license, express, implied or otherwise, is granted under any
  patents, copyrights or other intellectual property rights of NEC or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative
  purposes in semiconductor product operation and application examples. The incorporation of these
  circuits, software and information in the design of customer's equipment shall be done under the full
  responsibility of customer. NEC assumes no responsibility for any losses incurred by customers or third
  parties arising from the use of these circuits, software and information.
- While NEC endeavours to enhance the quality, reliability and safety of NEC semiconductor products, customers
  agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize
  risks of damage to property or injury (including death) to persons arising from defects in NEC
  semiconductor products, customers must incorporate sufficient safety measures in their design, such as
  redundancy, fire-containment, and anti-failure features.
- NEC semiconductor products are classified into the following three quality grades:
  - "Standard", "Special" and "Specific". The "Specific" quality grade applies only to semiconductor products developed based on a customer-designated "quality assurance program" for a specific application. The recommended applications of a semiconductor product depend on its quality grade, as indicated below. Customers must check the quality grade of each semiconductor product before using it in a particular application.
  - "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
  - "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
  - "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC semiconductor products is "Standard" unless otherwise expressly specified in NEC's data sheets or data books, etc. If customers wish to use NEC semiconductor products in applications not intended by NEC, they must contact an NEC sales representative in advance to determine NEC's willingness to support a given application.

(Note

- (1) "NEC" as used in this statement means NEC Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC semiconductor products" means any semiconductor product developed or manufactured by or for NEC (as defined above).